H igh-sensitivity m icrow ave vector detection at extrem ely low -pow er levels for low -dim ensional electron system s

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W e present a high-sensitivity m icrow ave vector detection system for studying the low-dimensional electron system embedded in the gaps of a coplanar waveguide at low tem peratures. U sing this system, we have achieved 0.005% and 0.001° resolutions in am plitude and phase variations, respectively, at 10 G H z in a magnetotransport measurement on a quantum -w ire array with an average signal power less than 75 dBm into the sample at 0.3 K. From the measured phase variation, we can distinguish a very tiny change in the induced dipole moment of each quantum w ire.

Coplanar waveguides (CPW 's) have been successfully used as broadband sensors in investigating the high-frequency magnetotransport phenomena of lowdimensional electron systems (LDES's), such as twodimensional electron systems $(2D \in S's)$, 1,2,3,4,5 and anti quantum dots (Q D 's),⁶ etc. In these works, a commercial vector network analyzer (VNA) is the major tool to measure the variation of the propagation constant, including the attenuation constant () and the phase constant (), of the CPW that containing the active LDES in the gaps between the metal electrodes. From and one can extract the longitudinal conductivity ($_{\rm xx}$)¹ (both real and im aginary parts) of the LDES. However, since the microw ave power delivered to sam ples at tem perature (T) below few hundred mK must be very low, the resolution of the data becom es very poor, especially for the phase part. Thus in most of the previous studies using CPW sensors, they only presented R ef xxg data derived from

and discarded the phase part. Even though Hohls et al.⁷ and Lew is et al.⁸ have addressed the Im f $_{xx}g$ behavior in the integer quantum Hall (IQ H) regime based on other techniques, still, the resolution of Im f $_{xx}g$ is mediocre due to the constrain of VNA's. Nevertheless, Im f $_{xx}g$, proportional to the change of the real part of dielectric constant, gives in portant inform ation about the electric polarization, that is of special interest in the case of Q D's, quantum w ires (Q W 's), or 2D ES's at high m agnetic elds (B). Furtherm ore, the relatively sm all e ective area of Q D's or Q W 's com pared to 2D ES sam ples leads to a very sm all signal variation (or dynam ic range), that m akes the conventional VNA m easurem ent very difcult and im practical.

In this letter, we present a new detection scheme and the instrum ental in plem entation, which can resolve very sm all variations not only in the am plitude but also the phase of an extrem ely low -power-level m icrow ave signal traveling through a CPW with LDES's embedded in the gaps while some external sam ple parameters, such as the applied m agnetic eld (B) or T, etc., is changed. The data of a low -T m agnetotransport m easurement on a QW -array sam ple m anifest the high-resolution capability of this system.

A simplied schematic diagram to illustrate the principle of phase detection by a phase-lock loop⁹ (PLL) is depicted in Fig. 1 (a). The CPW sample is connected to a PLL through two sem irigid coaxial cables of total length L. The PLL will force the total phase change (), including the phase change of the sem irigid cables $_{\rm L}$) and the CPW $\,$ sam ple ($\,$ $_{\rm s}$), to be 0 by tuning the (frequency (f) of the voltage-controlled oscillator (VCO) s = 0, during the experim ents, that is, = L + s = $_{\rm L}$. Hence s can be obtained directly or from the frequency change (f) of VCO via

=
$$_{\rm L}$$
 = 2 fL= $v_{\rm L}$ = ! $_{\rm L}$; (1)

where v_L is the phase velocity of the signal in the cable. The result can be expressed as the product of the change of the angular frequency (!) and the delay time (_L) of the connecting cables with a di erent sign.

A complete block diagram, including the pulse handling circuits, the microwave PLL, and the amplitude readout circuit, together with the CPW sample in a cryogenic environment, is shown in Fig.1 (b). The microwave part of this system is basically a pair of hom odyne detectors (mixers) with reference signals of quadrature phase di erence. One of the mixers with 0° reference (LO 1), used as the phase sensitive detector (PSD), has zero output (IF 1) forced by the PLL, while the other one with

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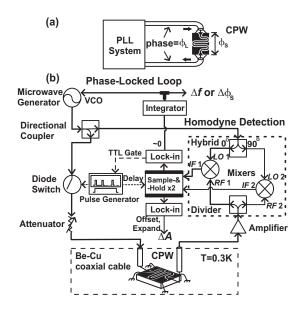


FIG.1: (a) Simplied schematic diagram for phase detection using a PLL. (b) Block diagram of the vector detection system. The meandering CPW containing a LDES in the gaps is part of the microwave signal path in the PLL.

90° reference (LO 2) has an output (IF 2) proportional to the amplitude of the signal.

Besides hom odyne detection we em ploy a double-pulse m odulation scheme to detect and average the microwave signal. A short pulse train with a 0.2 2 s pulse width and a 0.1 10% duty cycle, provided by a pulse generator and gated by a slow square-wave TTL signal with a period of 1 10 m s from a lock-in amplier, modulates the m icrow ave signal sent to the sam ple. A tim e-delayed pulse with a 0.1 1 spulse width triggered by the modulating pulses controls a sam ple-and-hold (S&H) circuit that samples the F output of the microwave mixer. The holding capacitor in the S&H circuit is discharged through an analog switch when the TTL gating signal is low. Finally the lock-in amplier reads the output of the S&H circuit. There are two sets of pulse averaging circuits, one for the PLL and the other for the am plitude readout. Note that the tim e constant of the lock-in am pli er for the PLL is about 1 30 m s, in contrast to 300 m s or 1 s for the am plitude readout part. The average of the PSD output (IF 1) is sent to an integrator (loop

lter of PLL) with a time constant of 26.3 m s. The output of the integrator connects to the FM input of the m icrowave source (VCO), thus closing the PLL. In fact this PLL system is modiled from what people used in surface-acoustic-wave detection experiments, 10 but with im proved pulse averaging and am plitude detection m ethods.

W e use three sets of m icrow ave m odules to cover the frequency from about 60 M H z to 18 G H z. The details of our instrum entations and circuit designs will be published elsewhere. To gain an idea of the detection lim it, we tested our system with only an 11 m sem irigid ca-

ble connected to the PLL without samples. The input m icrow ave signal is attenuated down to 70 dBm peak power, and less than 90 dBm in average. The background phase uctuation we obtain in this test is less than 0.0003° (root-m ean-squared value) for f. 6GHz and 0.006° for 6. f. 18 G H z, which is rem arkably low for such a low-power signal. In fact, the signal power reaching the low-noise amplier (LNA) is even lower than the input value claim ed above due to the loss of the cable, which is about 9 dB at 1 GHz and raises to 41 dB at 10 GHz. This may explain why the noise in phase increases at high frequencies. The resolution with a low-T sample loaded is slightly worse due to the loss of the sam ple and extra noise from the cryogenic environment. The resolution of the am plitude readout for a sm all-variation signal can be enhanced by the use of the "o set" and "expand" functions of the lock-in am pli er.¹¹

In the following we will present measured results for a QW array sample to demonstrate the resolving power of this method. The sample is fabricated from a standard M BE-grown m odulation-doped G aA s/A IG aA s heterostructure containing a 2DES, which is 150 nm under the surface. The 2DES has a mobility of about $1.5 \ 10^5$ $m^2 = V s at 4K$, and a density of 1.1 $10^{11} m^2$. Before evaporating the Cr/Au (10/300 nm) m etal layers for the CPW pattern, we etch away the 2DES part underneath. The widths of the center conductor and the gap of the CPW are 36 m and 23 m, respectively. A me-50 andering pattern¹ is used to increase the e ective length of the CPW . Subsequently we pattern the 2DES left in the gap into about 7000 identical QW m esas, each of 0.7 m wide and 20 m long, by using e-beam lithography and chem ical etching [Fig. 2 (a)]. The QW 's, parallel to the propagating direction of m icrowave signals, occupy only about 6 mm in length of the straight sections of the meandering CPW .

The CPW sample is immersed in liquid ³He (0.3 K) with applied B perpendicular to the sample surface. The total time delay given by the connection cables and microwave modules is 51.1 ns. From Eq.1, this time delay multiplied by f gives the phase change ($_{\rm s}$) of the CPW sample. Here f can be either obtained from the output voltage of the integrator in the PLL scaled with the FM deviation setting of the VCO, or measured directly with a microw ave counter. The peak power of the pulsed microw ave signals is 50 dBm (about 66 dBm in average) at the input end of the sem irigid cable.

Figure 2 (b) displays low - eld results for both directions of B. Besides the apparent Shubinkov-de-H ass oscillations, we can observe additional intriguing features for B below 0.2 T.For frequency higher than few GHz, the high-B data exhibit behaviors similar to a 2DES, showing IQH states. The SdH oscillations become less pronounced at lower f and even completely disappear below 600 M Hz. In Fig.2 (c), the data are shown up to B = 11 T.An extra adsorption peak appears at B = 6 Tassociated with a unique phase change nearby for f = 255M Hz, and m oves to lower B for higher f, indicating that

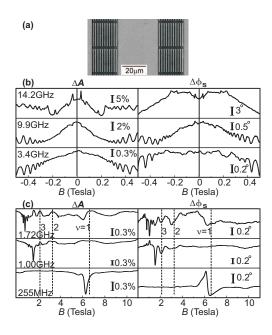


FIG.2: (a) Simplied schematic diagram for phase detection using a PLL. (b) Block diagram of the vector detection system. The meandering CPW containing a LDES in the gaps is part of the microwave signal path in the PLL.

this feature relates to the edge m agnetoplasm a^{12} (EMP) excitations. M ore detailed data and explanation of these interesting results will be published separately. Here we willem phasizem aimly the resolution of them easurements and also the polarization of each QW that can be extracted from our data.

The background noise of the data shown in Fig.2 (b) and (c) is extremely low. The amplitude and phase uctuations in A and $_{\rm s}$ data are less than 0.003% and 0.001° for f. 10 G H z, and 0.05% and 0.03° for f & 10 G H z, respectively. These resolution lim its actually depend on the power reaching the LNA, which is f dependent due to

the loss of the sam ple and the sem irigid cables. The average power into the sam ple and into the LNA are about -70 dBm and -76 dBm at f 1 G H z, and down to -80 dBm and -107 dBm at 14 G H z, respectively. Moreover, the 0.3 % scale bar in the A plot is equivalent to only 53 nS 2D conductivity in average, which is very sm all com pared to the signal levels in previous studies.^{1,2,3,4,5,6}

The susceptibility of each QW and _s can be related¹³ by = $s^{2}=N ! Z_{0}$; where N is the total num ber of QW 's, Z_0 the characteristic in pedance of the CPW, and a length scale related to the distribution of the tangential electric eld (E) on the surface and the geom etry of the CPW . The induced dipole m om ent of each QW seqment, p, is then E. For our CPW structure, is about 21 m. The value corresponding to the 0.2° scale bar in Fig.2(c) for 255M Hz is about 3 10^{27} F/m². For a signal of 51.5 dBm peak power, we can estimate paccordingly to be about 3 10 ²⁵ Cm, equivalent to about 17 electrons being transferred across a 0.1 m e ective QW width, assuming a 0.3 m depletion length near each edge.

Finally, we want to discuss the e ect of the cable length and related instrum ental considerations. U sually as we increase L, the sensitivity in phase is increased according to Eq.1, and so is the loop gain of the PLL. How ever, if L is too big, the PLL will have a very sm all capture range, and the e ect of noise and drift in electronic components becom e serious. In addition, high-frequency signals will su er a very severe loss.

In conclusion, we have developed and demonstrated a high-sensitivity vector detection system for very low – powerm icrowave signals used in a CPW broadband sensor. This system is a very powerful tool in studying the dynam ic behaviors, including the electric polarizations, of LDES's at low tem peratures.

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- ¹³ This equation can be derived simply by equating the energy stored in the eld for the electric dipole moment of all the QW 's, N E²=2, and the energy increment due to change of the e ective capacitance per unit length, CV ²=2. The length scale can be shown to be $[2 (C_a = _0)hV^2 = E^2i]^{1-2}$, where C_a is the capacitance of the CPW if the substrate is replaced by air, and $hV^2 = E^2i$ is the average of square of voltage signal over square of tangential eld on the surface across the gap of the CPW.